**Product data sheet** 

# 1. Product profile

# 1.1. General description

PNP medium power transistors in a medium power SOT223 (SC73) Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number	Package	NPN comlement	
	Nexperia	JEDEC	
BCP51T	SOT223	SC-73	BCP54T
BCP51-10T			BCP54-10T
BCP51-16T			BCP54-16T

#### 1.2. Features and benefits

- High collector current capability  $I_C$  and  $I_{CM}$
- · Three current gain selections
- High power dissipation capability
- · AEC-Q101 qualified

## 1.3. Applications

- · Linear voltage regulators
- MOSFET drivers
- · High-side switches
- Power management
- Amplifiers

#### 1.4. Quick reference data

Table 2. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-45	V
I <sub>C</sub>	collector current		-	-	-1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-2	Α



### 45 V, 1 A PNP medium power transistors

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
h <sub>FE</sub>	DC current gain						
	BCP51T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	250	
	BCP51-10T		[1]	63	-	160	
	BCP51-16T		[1]	100	-	250	

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

# 2. Pinning information

#### Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	Ç
2	С	collector		B—
3	E	emitter		, h
4	С	collector	□1 □2 □3	Ë sym132

# 3. Ordering information

#### **Table 4. Ordering information**

Type number	Package	Package					
	Name	Description	Version				
BCP51T	SC-73	plastic, surface-mounted package with increased heatsink;	SOT223				
BCP51-10T		4 leads					
BCP51-16T							

# 4. Marking

#### Table 5. Marking

Table of marking					
Type number	Marking code				
BCP51T	BCP51T				
BCP51-10T	P5110T				
BCP51-16T	P5116T				

2/14

#### 45 V, 1 A PNP medium power transistors

# 5. Limiting values

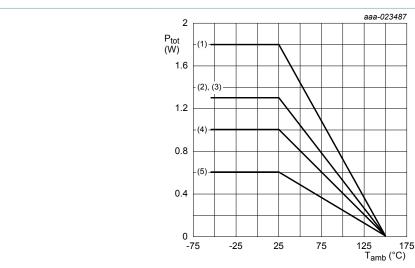
#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	open emitter		-45	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-45	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-2	Α
I <sub>B</sub>	base current			-	-0.2	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-0.3	Α
P <sub>tot</sub> total power dissipation	total power dissipation T <sub>amb</sub> ≤ 25 °C	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.6	W
			[2]	-	1	W
			[3]	-	1.3	W
			[4]	-	1.3	W
			[5]	-	1.8	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.
- [5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm.<sup>2</sup>



- (1) FR4 PCB; 4-layer copper; 1 cm<sup>2</sup>
- (2) FR4 PCB; single-sided copper; 6 cm<sup>2</sup>
- (3) FR4 PCB; 4-layer copper; standard footprint
- (4) FR4 PCB; single-sided copper; 1 cm<sup>2</sup>
- (5) FR4 PCB; single-sided copper; standard footprint

#### Fig. 1. Power derating curves

### 45 V, 1 A PNP medium power transistors

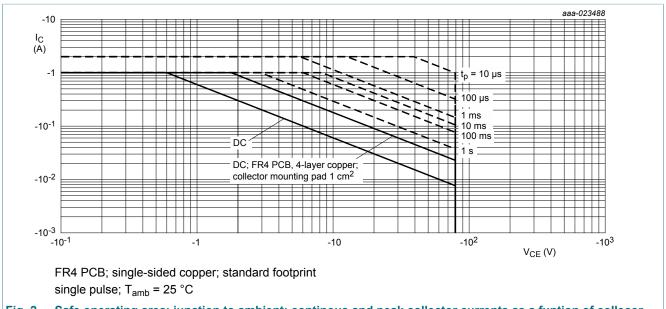


Fig. 2. Safe operating area; junction to ambient; continous and peak collector currents as a funtion of collecoremitter voltage

#### 45 V, 1 A PNP medium power transistors

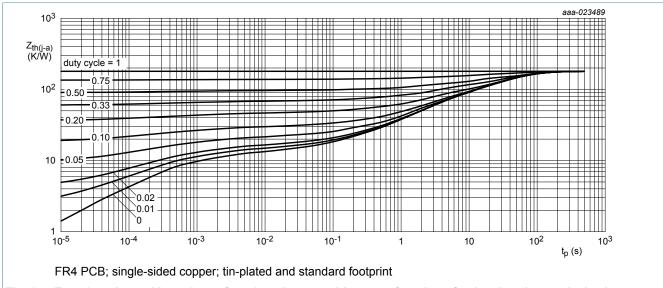
### 6. Thermal characteristics

#### **Table 7. Thermal characteristics**

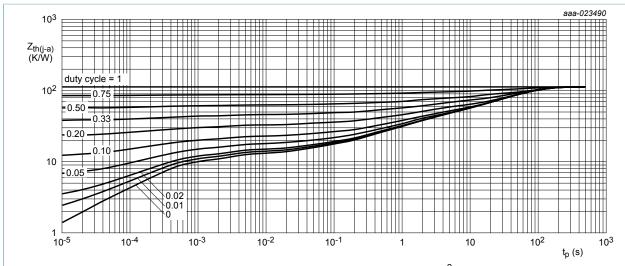
 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	209	K/W
		[2]			125	K/W	
			[3]			97	K/W
			[4]	-	-	97	K/W
			[5]	-	-	70	K/W
R <sub>(j-sp)</sub>	thermal resistance from junction to solder point			-	-	18	K/W

- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>. [3]
- Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint. [4]
- [5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

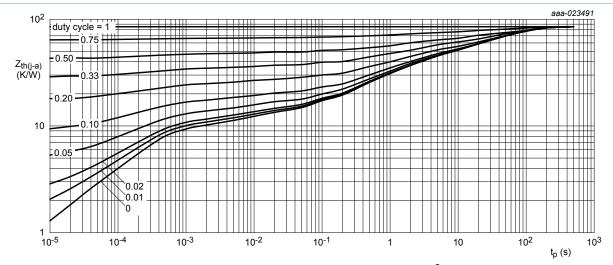


#### 45 V, 1 A PNP medium power transistors



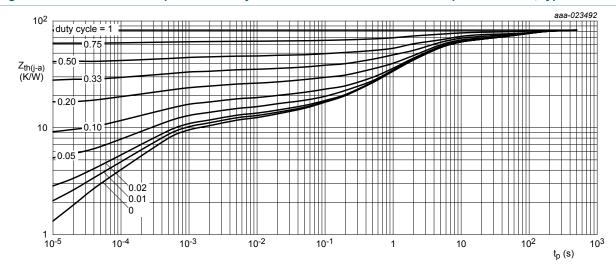
FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>

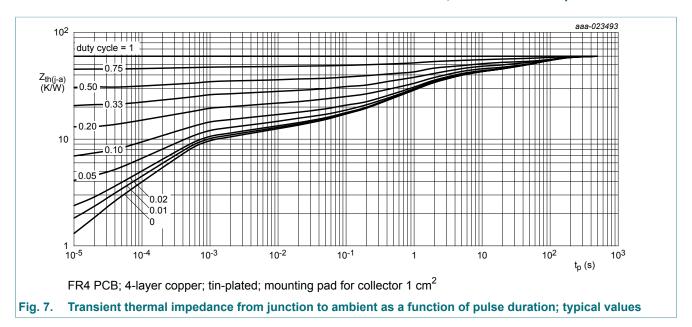
Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; 4-layer copper; tin-plated and standard footprint

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 45 V, 1 A PNP medium power transistors



## 7. Characteristics

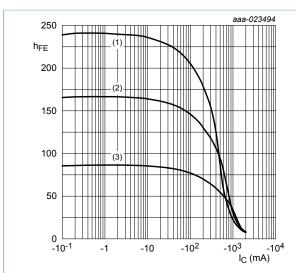
#### **Table 8. Characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \ \mu A; \ I_E = 0 \ A$		-45	-		V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_E = 0 \text{ A}$		-45	-		V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I <sub>E</sub> = -100 μA; I <sub>C</sub> = 0 A		-5	-		V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A		-	-	-100	nA
	cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	-10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A		-	-	-100	nA
h <sub>FE</sub> DC current gain			,				
	BCP51T, -10T, -16T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -5 mA		63	-	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA	[1]	40	-	-	
	BCP51T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	250	
	BCP51-10T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	160	
	BCP51-16T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -500 \text{ mA}$ ; $I_B = -50 \text{ mA}$	[1]	-	-	-500	mV
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA	[1]	-	-	-1	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -50 mA; f = 100 MHz		100	140	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	7	-	pF

[1] pulsed;  $t_0 \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

#### 45 V, 1 A PNP medium power transistors



$$V_{CE}$$
 = -2  $V$ 

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. DC current gain as a function of collector current; typical values

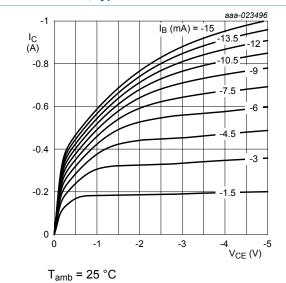
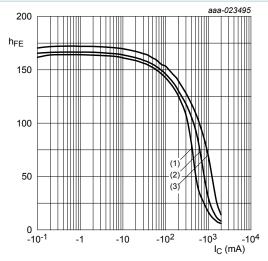


Fig. 10. Collector current as a function of collectoremitter voltage; typical values

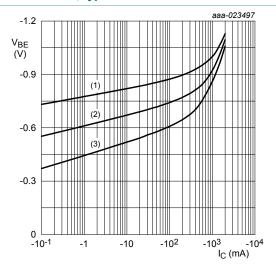


(1) 
$$V_{CE} = -1 V$$

(2) 
$$V_{CE} = -2 V$$

(3) 
$$V_{CE} = -5 V$$

Fig. 9. DC current gain as a function of collector current; typical values



$$V_{CE}$$
 = -2  $V$ 

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

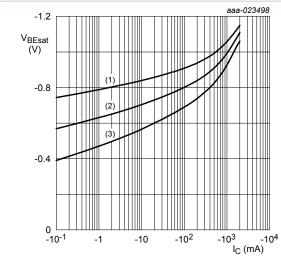
(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb}$$
 = 100 °C

Fig. 11. Base-emitter voltage as a function of collector current; typical values

8 / 14

#### 45 V, 1 A PNP medium power transistors



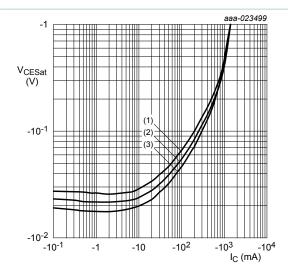
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 12. Base-emitter saturation voltage as a function of Fig. 13. Collector-emitter saturation voltage as a collector current; typical values



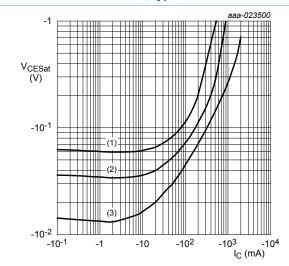
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

function of collector current; typical values



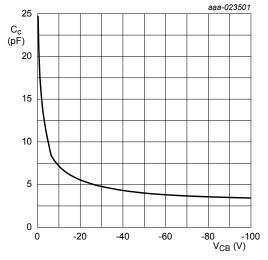
 $T_{amb}$  = 25 °C

(1) 
$$I_C/I_B = 50$$

(2) 
$$I_C/I_B = 20$$

(3)  $I_C/I_B = 5$ 

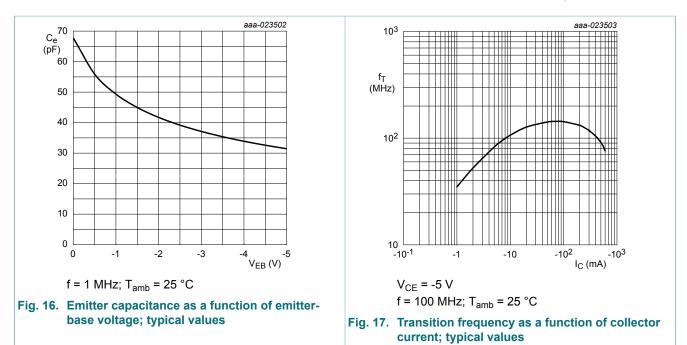
Fig. 14. Collector-emitter saturation voltage as a function of collector current; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

Fig. 15. Collector capacitance as a function of collectorbase voltage; typical values

#### 45 V, 1 A PNP medium power transistors

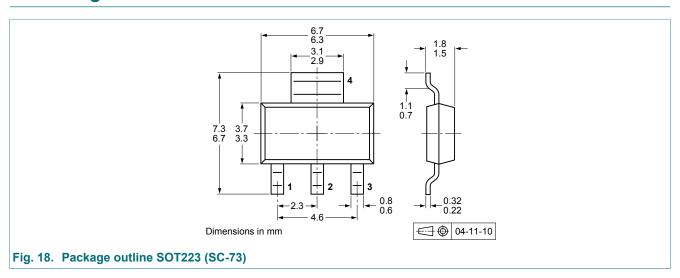


## 8. Test information

## 8.1. Quality information

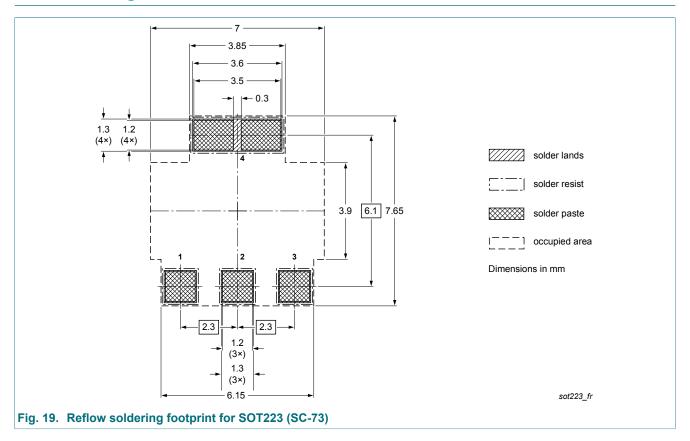
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

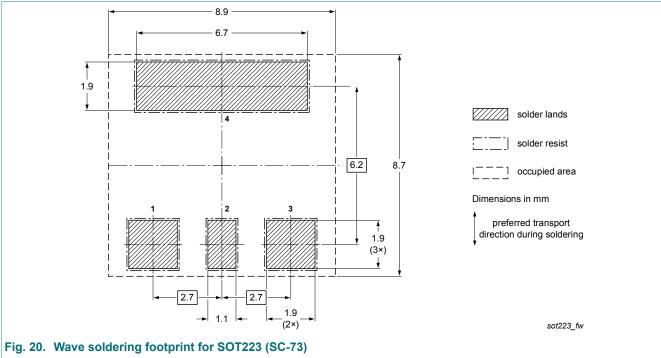
# 9. Package outline



#### 45 V, 1 A PNP medium power transistors

# 10. Soldering





45 V, 1 A PNP medium power transistors

# 11. Revision history

#### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCP51T_SER v.1	20190429	Product data sheet	-	-

12 / 14

# 12. Legal information equipmen product or severe product or severe

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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## 45 V, 1 A PNP medium power transistors

# **Contents**

1. Product profile	1
1.1. General description	1
1.2. Features and benefits	1
1.3. Applications	1
1.4. Quick reference data	1
2. Pinning information	2
3. Ordering information	2
4. Marking	2
5. Limiting values	3
6. Thermal characteristics	5
7. Characteristics	7
8. Test information	10
8.1. Quality information	10
9. Package outline	10
10. Soldering	
11. Revision history	12
12. Legal information	13

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 29 April 2019

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